TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type

SSM3K121TU

Power Management Switch Applications High-Speed Switching Applications

• 1.5 V drive

• Low ON-resistance: $R_{on} = 140 \text{ m}\Omega \text{ (max) (@V_{GS} = 1.5 V)}$

 $R_{On} = 93 \text{ m}\Omega \text{ (max) (@V_{GS} = 1.8 V)}$ $R_{On} = 63 \text{ m}\Omega \text{ (max) (@V_{GS} = 2.5 V)}$ $R_{On} = 48 \text{ m}\Omega \text{ (max) (@V_{GS} = 4.0 V)}$

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V_{DS}	20	V	
Gate-Source voltage		V _{GSS}	± 10	V	
Drain current	DC	I _D	3.2	Α	
	Pulse	I _{DP}	6.4		
Drain power dissipation		P _D (Note 1)	800	mW	
		P _D (Note 2)	500		
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

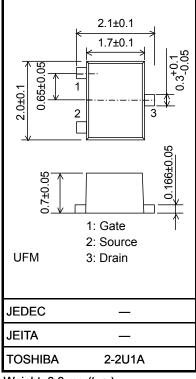
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Mounted on a ceramic board. (25.4 mm \times 25.4 mm \times 0.8 t, Cu Pad: 645 mm 2)

Note 2: Mounted on a FR4 board. (25.4 mm \times 25.4 mm \times 1.6 t, Cu Pad: 645 mm²)

Unit: mm



Weight: 6.6 mg (typ.)

Electrical Characteristics (Ta = 25°C)

Charac	teristics	Symbol	Test Condition		Min	Тур.	Max	Unit
Drain-Source breakdown voltage		V (BR) DSS	$I_D = 1 \text{ mA}, V_{GS} = 0$		20	_	_	V
		V (BR) DSX	$I_D = 1 \text{ mA}, V_{GS} = -10 \text{ V}$	12	_	_		
Drain cutoff currer	nt	I _{DSS}	$V_{DS} = 20 \text{ V}, V_{GS} = 0$		_	_	1	μА
Gate leakage curr	ent	I _{GSS}	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0$		_	_	±1	μА
Gate threshold vo	Itage	V _{th}	$V_{DS} = 3 \text{ V}, I_{D} = 1 \text{ mA}$		0.35	_	1.0	V
Forward transfer a	admittance	Yfs	$V_{DS} = 3 \text{ V}, I_{D} = 2.0 \text{ A}$	(Note 3)	6.5	13	_	S
	R _{DS} (ON)	$I_D = 2.0 \text{ A}, V_{GS} = 4.0 \text{ V}$	(Note 3)	_	36	48	mΩ	
Drain-Source ON-resistance		$I_D = 2.0 \text{ A}, V_{GS} = 2.5 \text{ V}$	(Note 3)	_	46	63		
		I _D = 1.0 A, V _{GS} = 1.8 V	(Note 3)	_	60	93		
		I _D = 0.5 A, V _{GS} = 1.5 V	(Note 3)	_	75	140		
Input capacitance		C _{iss}			_	400	_	
Output capacitance		Coss	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$		_	68	_	pF
Reverse transfer of	er capacitance C _{rss}			_	60	_		
Total Gate Charge	Э	Qg			_	5.9	_	
Gate-Source Charge		Q _{gs}	V_{DS} = 10 V, I_{DS} = 3.2 A, V_{GS} = 4 V		_	4.1	_	nC
Gate-Drain Charge		Q _{gd}			_	1.8	_	
Switching time	Turn-on time	t _{on}	$V_{DD} = 10 \text{ V}, I_D = 2 \text{ A},$ $V_{GS} = 0 \text{ to } 2.5 \text{ V}, R_G = 4.7 \Omega$		_	14		ns
	Turn-off time	t _{off}			_	15	_	
Drain-Source forward voltage		V_{DSF}	$I_D = -3.2 \text{ A}, V_{GS} = 0 \text{ V}$	(Note 3)	_	-0.85	-1.2	V

Note 3: Pulse test

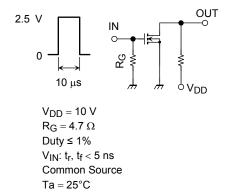
Start of commercial production 2006-11

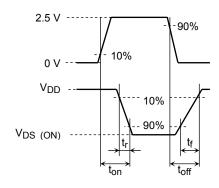
Switching Time Test Circuit

(a) Test Circuit

(b) V_{IN}

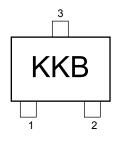
(c) Vout

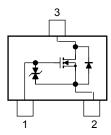




Marking

Equivalent Circuit (top view)





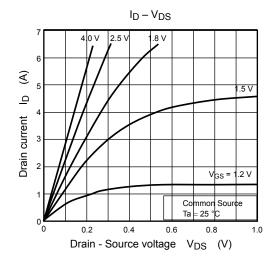
Notice on Usage

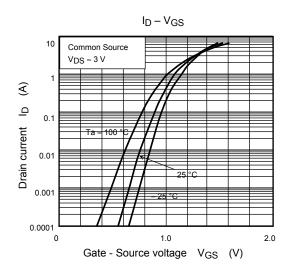
 V_{th} can be expressed as the voltage between gate and source when the low operating current value is I_D = 1 mA for this product. For normal switching operation, V_{GS} (on) requires a higher voltage than V_{th} , and V_{GS} (off) requires a lower voltage than V_{th} . (The relationship can be established as follows: V_{GS} (off) < V_{th} < V_{GS} (on).)

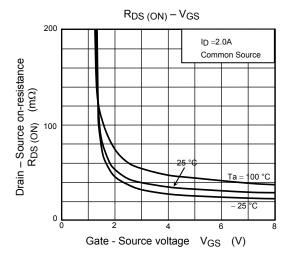
Take this into consideration when using the device.

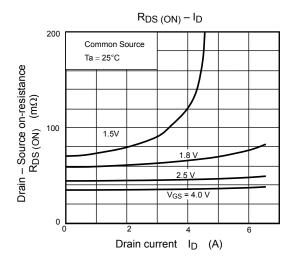
Handling Precaution

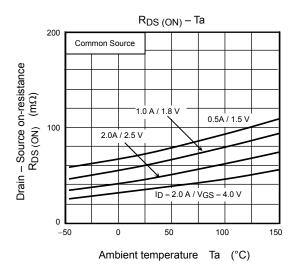
When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

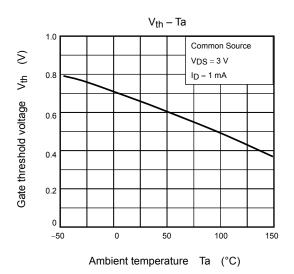


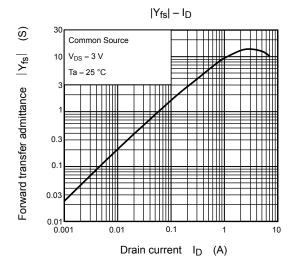


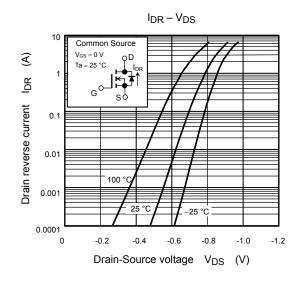


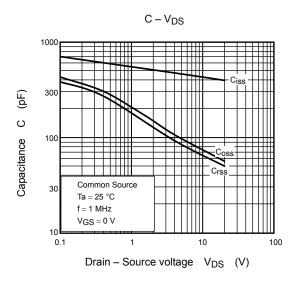


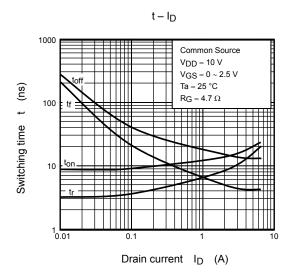


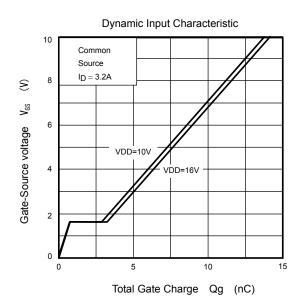






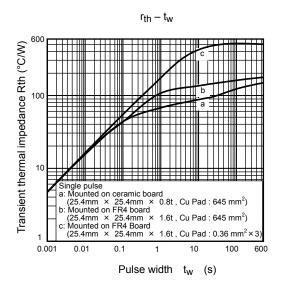


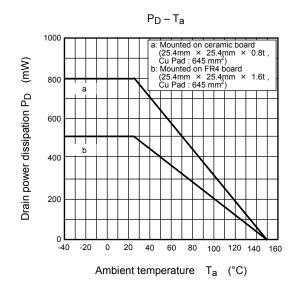




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